



FOUR TRANSISTORS (FTX-2A)
MODULE P/N 841557

361457

Functional Description

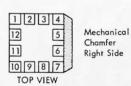
The Four Transistor, FTX-2A, module consists of four single transistors with the individual base, emitter and collector leads terminated at specific pins. The individual transistors offer the circuit designer uniformity of circuit packaging as well as flexibility in application with other SLT modules.

Schematic





Terminal Configuration



Maximum Ratings

I_E = 50 Milliamps

FTX-2A Test Conditions

	INDIVIDUAL DEVICE PARAMETER	TEST	S		
TESTS	TEST CONDITIONS	T ° C	LIMITS		
			MIN	MAX	UNITS
BVCEO	I _C = 5ma, I _B = 0	25	8		٧
BV _{CBO}	l _C = 10 μ α	25	12		V
BV _{EBO}	ΙΕ = 10 μα	25	2.5		٧
CEX	V _{CE} = 5V, V _{BE} = .35V	75		20	μα
IBEX	V _{CE} = 9V, V _{BE} = -3V	75		10	μα
H _{FE}	I _E = 0.1ma, V _{CB} = 0V	25	10		
H _{FE}	I _E = 1.0ma, V _{CB} = 0V	25	25		
H _{FE}	I _E = 10.0ma, V _{CB} = 0V	25	30		
H _{FE}	I _E = 50.0ma, V _{CB} = 0V	25	25		
τ,	See Figure 1	25		40	ns
/GAIN/	$f = 100 \text{ mhz}, I_E = 10 \text{ma}, V_{CB} = 3.0 \text{V}$	25	1.5		
C _{ib}	VEB = 0V, f = 1 ± .5 mhz	25		6.5	pf
C _{ob}	$V_{CB} = 0V, f = 1 \pm .5 \text{ mhz}$	25		6.5	pf
V _{CE}	I _C = 1.0ma, I _B = .05ma	25		.30	٧
V _{CE}	I _C = 10.0ma, I _B = .5ma	25		.30	٧
V _{CE}	I _C = 50.0ma, I _B = 2.5ma	25		.50	٧
V _{BE}	I _C = 1.0ma, I _B = .05ma	25	.60	.75	٧
V _{BE}	I _C = 10.0ma, I _B = .5ma	25	.70	.85	V
V _{BE}	I _C = 50.0ma, I _B = 2.5ma	25	.80	1.10	٧
h _{rb}	I _C = 1.0ma, V _{CB} = +1V, f = 10 mhz	25		.05	

$\tau_{\rm s}$ Test Circuit

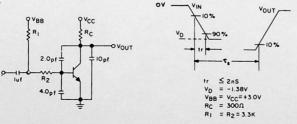


FIGURE 1